

SHARP

PC8141xNSZ Series

PC8141x NSZ Series

AC Input, Low Input Current  
Type Photocoupler

Features

- 1. Low input current type ( $I_F=0.5\text{mA}$ )
- 2. High resistance to noise due to high common rejection voltage (CMR:MIN.  $10\text{kV}/\mu\text{s}$ )
- 3. AC input type
- 4. Compact dual-in line package
- 5. Isolation voltage (Viso: $5\text{kVrms}$ )
- 6. Recognized by UL, file No. E64380

Applications

- 1. Programmable controllers
- 2. Facsimiles
- 3. Telephones

Rank Table

| Model No.  | Rank mark    | Ic (mA)     | Conditions                                                             |
|------------|--------------|-------------|------------------------------------------------------------------------|
| PC81410NSZ | A or no mark | 0.25 to 2.0 | $I_F=\pm 0.5\text{mA}$<br>$V_{CE}=5\text{V}$<br>$T_a=25^\circ\text{C}$ |
| PC81411NSZ | A            | 0.5 to 1.5  |                                                                        |

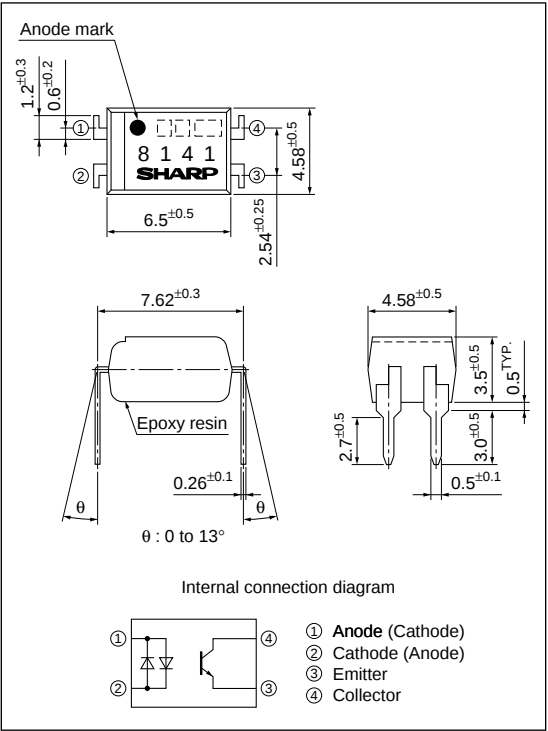
Absolute Maximum Ratings (Ta=25°C)

|        | Parameter                   | Symbol    | Rating      | Unit  |
|--------|-----------------------------|-----------|-------------|-------|
| Input  | Forward current             | $I_F$     | $\pm 10$    | mA    |
|        | *1 Peak forward current     | $I_{FM}$  | $\pm 200$   | mA    |
|        | Power dissipation           | P         | 15          | mW    |
| Output | Collector-emitter voltage   | $V_{CEO}$ | 70          | V     |
|        | Emitter-collector voltage   | $V_{ECO}$ | 6           | V     |
|        | Collector current           | $I_C$     | 50          | mA    |
|        | Collector power dissipation | $P_C$     | 150         | mW    |
|        | Total power dissipation     | $P_{tot}$ | 170         | mW    |
|        | Operating temperature       | $T_{opr}$ | -30 to +100 | °C    |
|        | Storage temperature         | $T_{stg}$ | -55 to +125 | °C    |
|        | *2 Isolation voltage        | $V_{iso}$ | 5           | kVrms |
|        | *3 Soldering temperature    | $T_{sol}$ | 260         | °C    |

\*1 Pulse width $\leq 100\mu\text{s}$ , Duty ratio=0.001  
\*2 40 to 60%RH, AC for 1 minute, f=60Hz  
\*3 For 10s

Outline Dimensions

(Unit : mm)



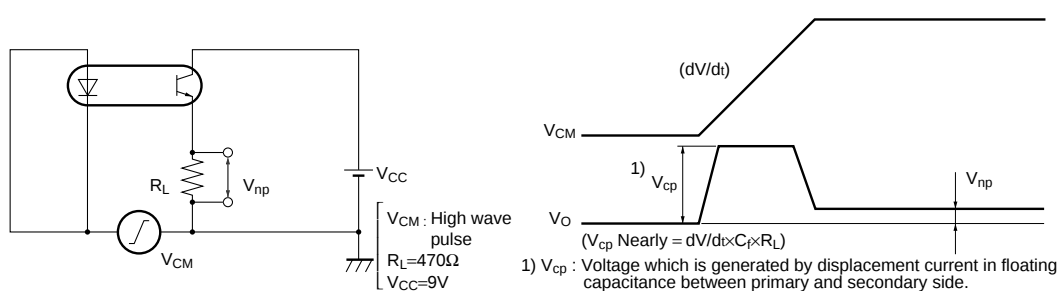
## ■ Electro-optical Characteristics

(Ta=25°C)

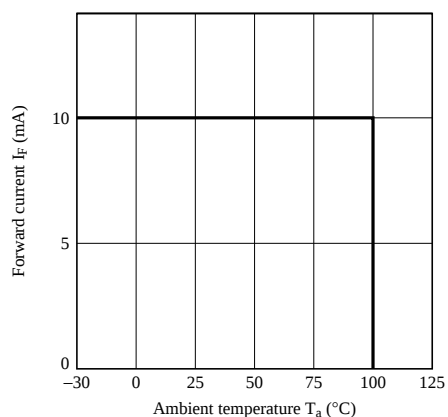
| Parameter                |                                      | Symbol                | Conditions                                  | MIN.                                                                                                                              | TYP.               | MAX. | Unit |       |
|--------------------------|--------------------------------------|-----------------------|---------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------|--------------------|------|------|-------|
| Input                    | Forward voltage                      | V <sub>F</sub>        | I <sub>F</sub> =±10mA                       | –                                                                                                                                 | 1.2                | 1.4  | V    |       |
|                          | Terminal capacitance                 | C <sub>t</sub>        | V=0, f=1kHz                                 | –                                                                                                                                 | 30                 | 250  | pF   |       |
| Output                   | Collector dark current               | I <sub>CEO</sub>      | V <sub>CE</sub> =50V, I <sub>F</sub> =0     | –                                                                                                                                 | –                  | 100  | nA   |       |
|                          | Collector-emitter breakdown voltage  | BV <sub>CEO</sub>     | I <sub>C</sub> =0.1mA, I <sub>F</sub> =0    | 70                                                                                                                                | –                  | –    | V    |       |
| Transfer characteristics | Emitter-collector breakdown voltage  | BV <sub>ECO</sub>     | I <sub>E</sub> =10μA, I <sub>F</sub> =0     | 6                                                                                                                                 | –                  | –    | V    |       |
|                          | Collector current                    | I <sub>C</sub>        | I <sub>F</sub> =±0.5mA, V <sub>CE</sub> =5V | 0.25                                                                                                                              | –                  | 2.0  | mA   |       |
|                          | Collector-emitter saturation voltage | V <sub>CE (sat)</sub> | I <sub>F</sub> =±10mA, I <sub>C</sub> =1mA  | –                                                                                                                                 | –                  | 0.2  | V    |       |
|                          | Isolation resistance                 | R <sub>ISO</sub>      | DC500V 40 to 60%RH                          | 5×10 <sup>10</sup>                                                                                                                | 1×10 <sup>11</sup> | –    | Ω    |       |
|                          | Floating capacitance                 | C <sub>f</sub>        | V=0, f=1MHz                                 | –                                                                                                                                 | 0.6                | 1.0  | pF   |       |
|                          | Response time                        | Rise time             | tr                                          | V <sub>CE</sub> =2V, I <sub>C</sub> =2mA, R <sub>L</sub> =100Ω                                                                    | –                  | 4    | 18   | μs    |
|                          |                                      | Fall time             | tf                                          |                                                                                                                                   | –                  | 3    | 18   | μs    |
|                          | *1 Common mode rejection voltage     |                       | CMR                                         | Ta=25°C, R <sub>L</sub> =470Ω, V <sub>CM</sub> =1.5kV (peak),<br>I <sub>F</sub> =0mA, V <sub>CC</sub> =9V, V <sub>np</sub> =100mV | 10                 | –    | –    | kV/μs |

\*1 Refer to Fig.1.

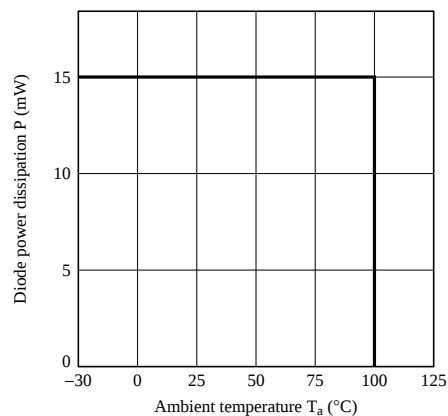
**Fig.1 Test Circuit for Common Mode Rejection Voltage**

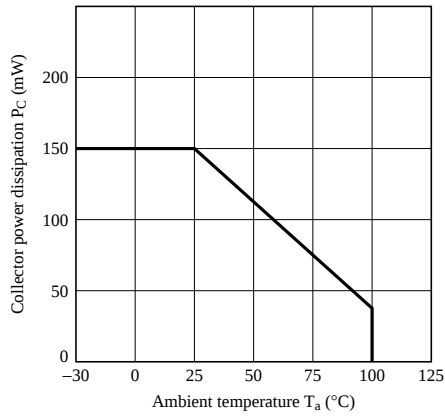
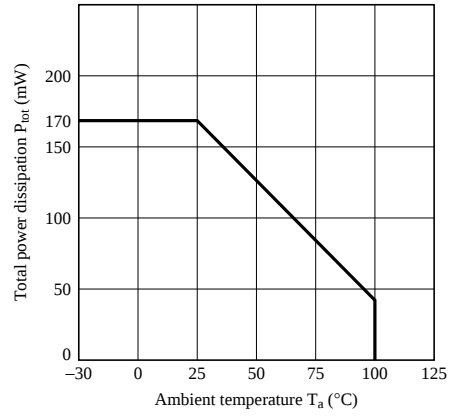
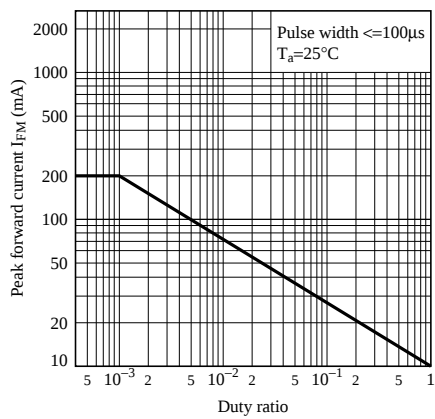
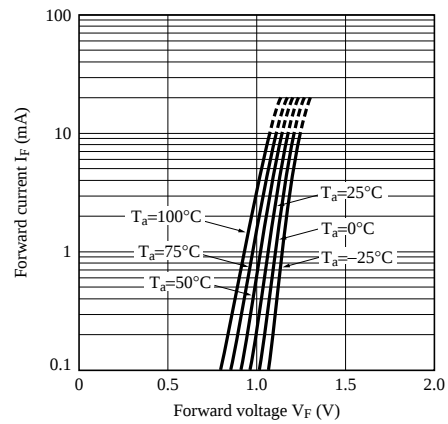
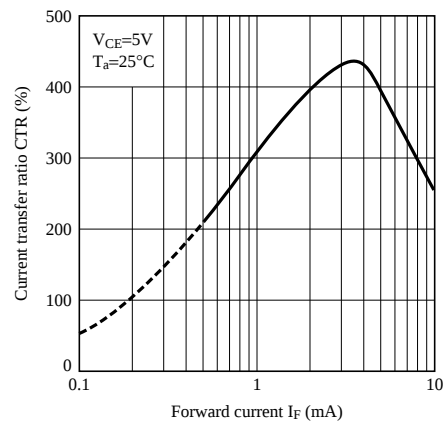
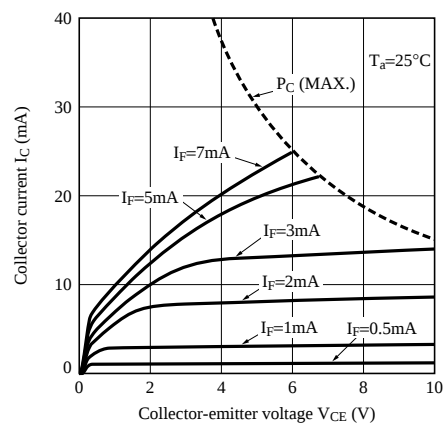


**Fig.2 Forward Current vs. Ambient Temperature**



### Fig.3 Diode Power Dissipation vs. Ambient Temperature



**Fig.4 Collector Power Dissipation vs. Ambient Temperature****Fig.5 Total Power Dissipation vs. Ambient Temperature****Fig.6 Peak Forward Current vs. Duty Ratio****Fig.7 Forward Current vs. Forward Voltage****Fig.8 Current Transfer Ratio vs. Forward Current****Fig.9 Collector Current vs. Collector-emitter Voltage**

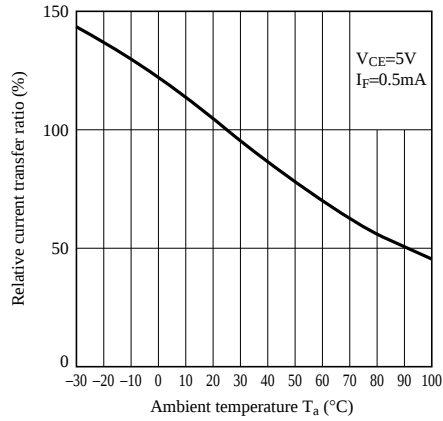
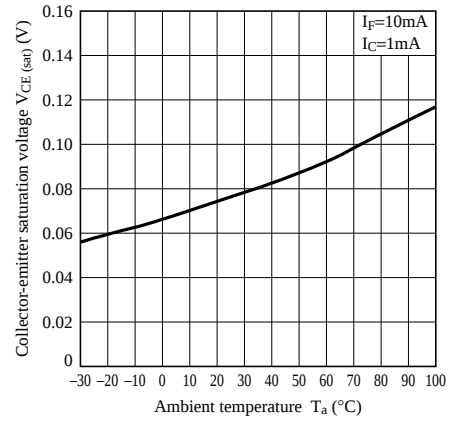
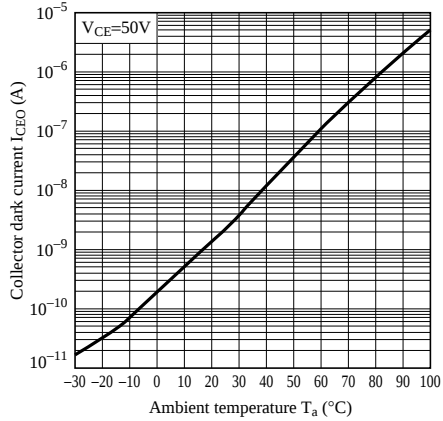
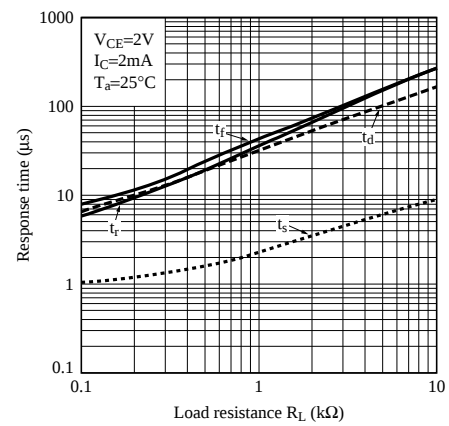
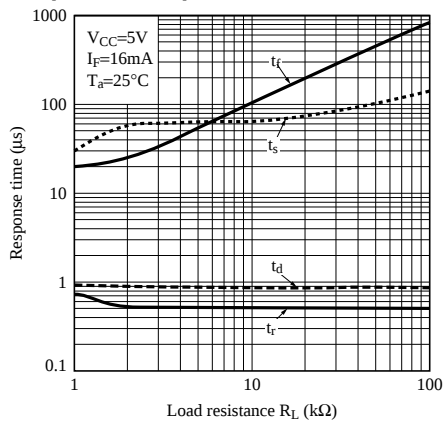
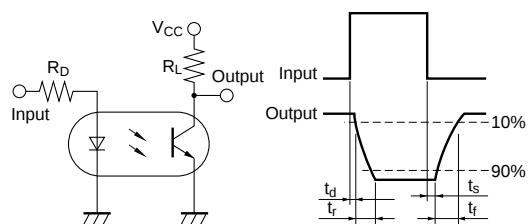
**Fig.10 Relative Current Transfer Ratio vs. Ambient Temperature****Fig.11 Collector - emitter Saturation Voltage vs. Ambient Temperature****Fig.12 Collector Dark Current vs. Ambient Temperature****Fig.13 Response Time vs. Load Resistance****Fig.14 Response Time vs. Load Resistance (Saturation)****Fig.15 Test Circuit for Response Time**

Fig.16 Voltage Gain vs Frequency

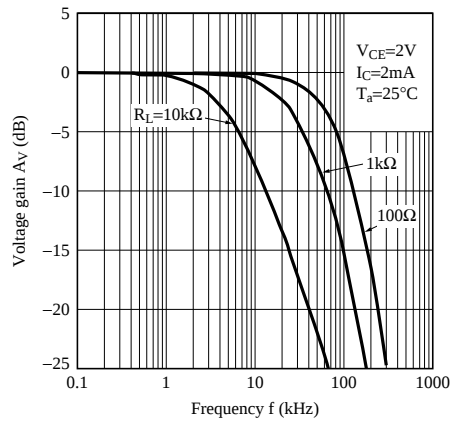


Fig.17 Collector-emitter Saturation Voltage vs. Forward Current

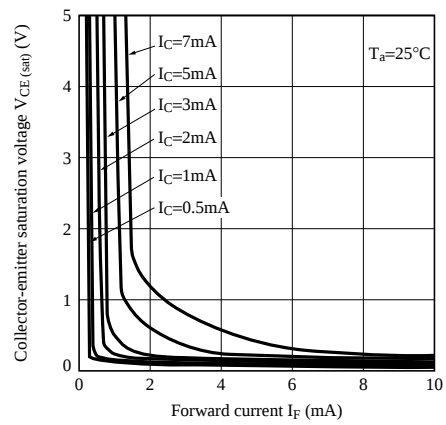


Fig.18 Reflow Soldering

Only one time soldering is recommended within the temperature profile shown below.

